

Technical Data Sheet

5mm Infrared LED , T-1 3/4

HIR333C-A

Features

- High reliability
- High radiant intensity
- Peak wavelength $\lambda_p=850\text{nm}$
- 2.54mm Lead spacing
- Low forward voltage

Descriptions

- EVERLIGHT'S Infrared Emitting Diode(HIR333C-A) is a high intensity diode , molded in a water clear plastic package.
- The device is spectrally matched with phototransistor , photodiode and infrared receiver module.



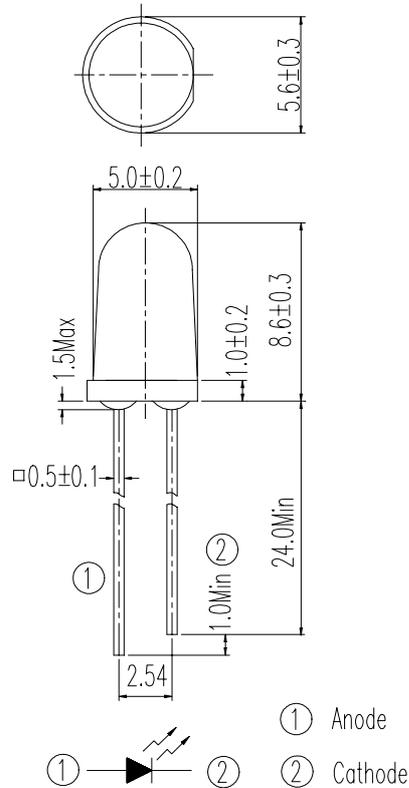
Applications

- Electronic toll collection system for freeway
- Infrared applied system

Device Selection Guide

LED Part No.	Chip	Lens Color
	Material	
HIR	GaAlAs	Water clear

Package Dimensions



- Notes:** 1.All dimensions are in millimeters
2.Tolerances unless dimensions $\pm 0.25\text{mm}$

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Units
Continuous Forward Current	I_F	100	mA
Peak Forward Current	I_{FP}	1.0	A
Reverse Voltage	V_R	5	V
Operating Temperature	T_{opr}	-40 ~ +85	°C
Storage Temperature	T_{stg}	-40 ~ +85	°C
Soldering Temperature	T_{sol}	260	°C
Power Dissipation at(or below) 25°C Free Air Temperature	P_d	150	mW

Notes: *1: I_{FP} Conditions--Pulse Width $\leq 100 \mu\text{s}$ and Duty $\leq 1\%$.

*2:Soldering time ≤ 5 seconds.

Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Units
Radiant Intensity	Ee	I _F =20mA	11	15	--	mW/sr
		I _F =100mA Pulse Width ≤ 100 μs ,Duty ≤ 1%	--	140	--	
		I _F =1A Pulse Width ≤ 100 μs ,Duty ≤ 1%.	--	980	--	
Peak Wavelength	λ p	I _F =20mA	--	850	--	nm
Spectral Bandwidth	Δ λ	I _F =20mA	--	45	--	nm
Forward Voltage	V _F	I _F =20mA		1.45	1.65	V
		I _F =100mA Pulse Width ≤ 100 μs ,Duty ≤ 1%	--	1.80	2.40	
		I _F =1A Pulse Width ≤ 100 μs ,Duty ≤ 1%.	--	4.10	5.25	
Reverse Current	I _R	V _R =5V	--	--	10	μ A
View Angle	2 θ 1/2	I _F =20mA	--	17	--	deg

Rank

 Condition : I_F=20mA

Unit : mW/sr

Bin Number	N	P	Q	R	S
Min	11.0	15.0	21.0	30.0	42.0
Max	17.6	24.0	34.0	48.0	67.0

Typical Electro-Optical Characteristics Curves

Fig.1 Forward Current vs. Ambient Temperature

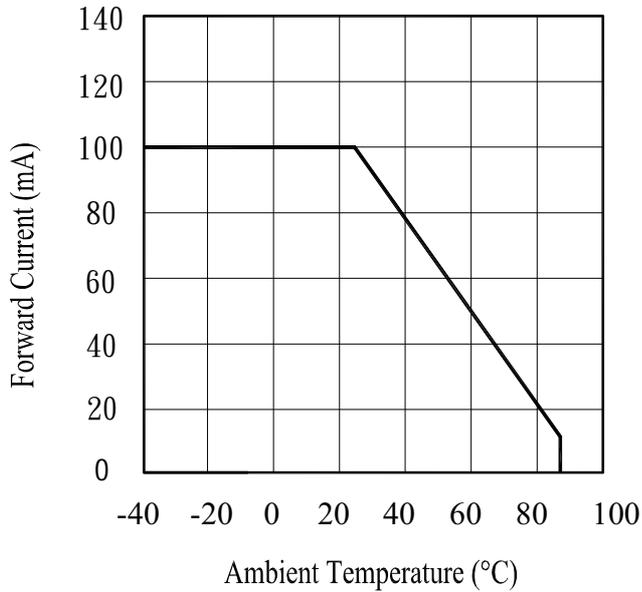


Fig.2 Spectral Distribution

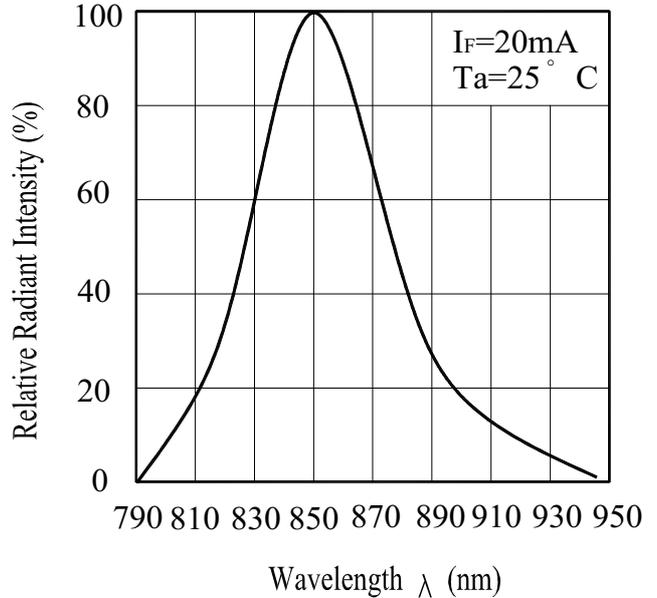


Fig.3 Peak Emission Wavelength vs. Ambient Temperature

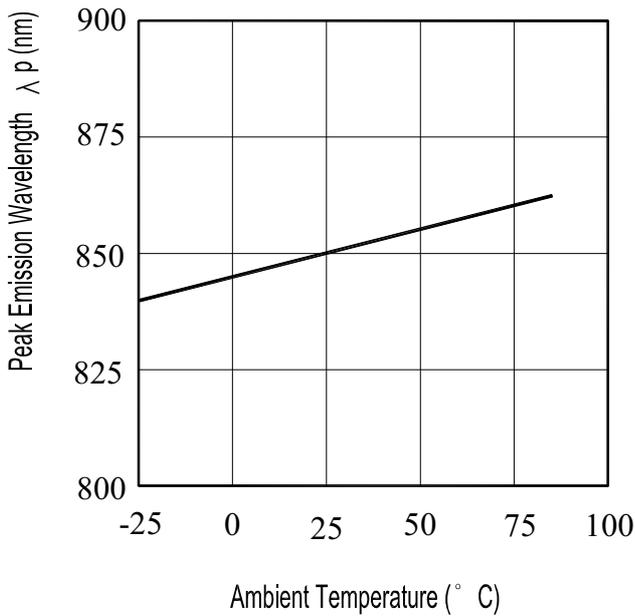
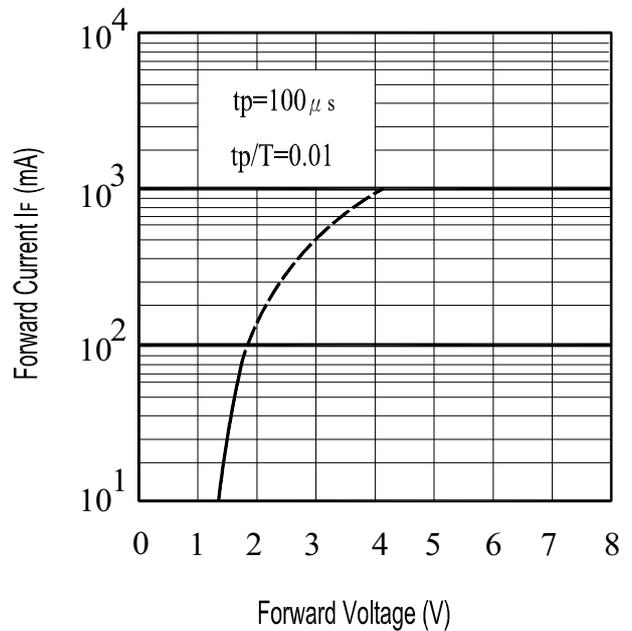


Fig.4 Forward Current vs. Forward Voltage



Typical Electro-Optical Characteristics Curves

Fig.5 Relative Intensity vs.
Forward Current

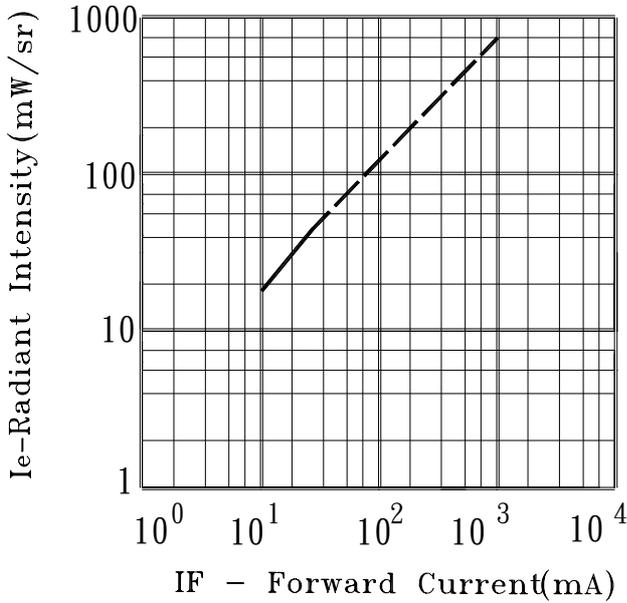


Fig.6 Relative Radiant Intensity vs.
Angular Displacement

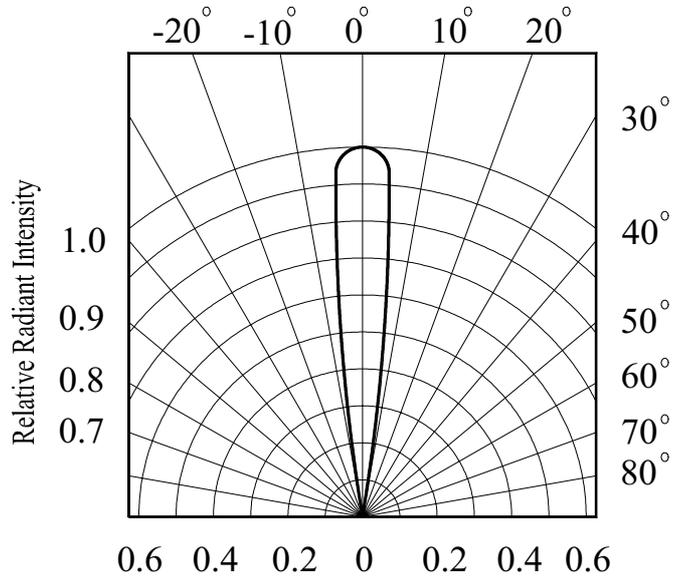


Fig.7 Relative Intensity vs.
Ambient Temperature ($^\circ$ C)

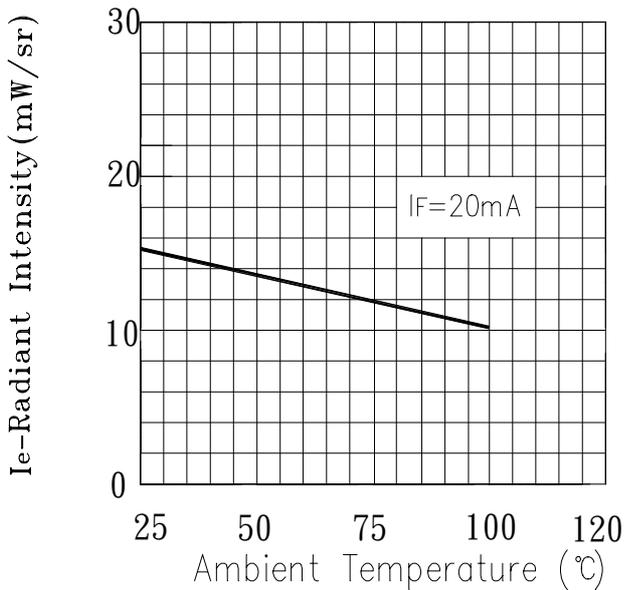
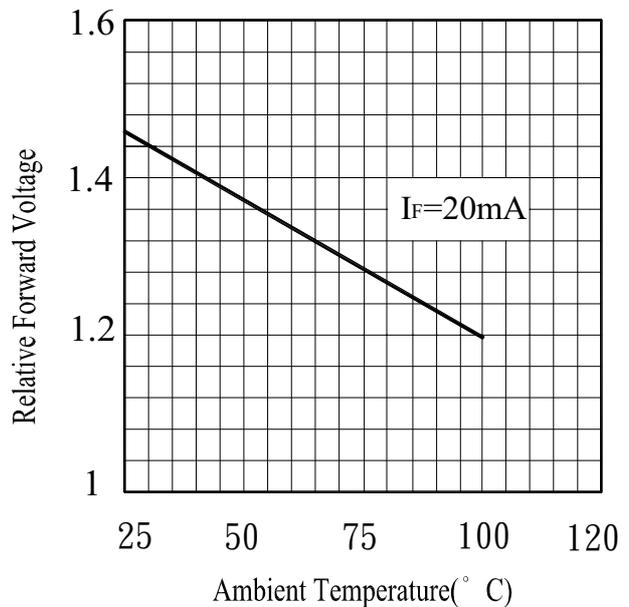


Fig.8 Forward Current vs.
Ambient Temperature ($^\circ$ C)





HIR333C-A

Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP. : 260°C ± 5°C	10secs	22pcs	$I_R \geq U \times 2$ $E_e \leq L \times 0.8$ $V_F \geq U \times 1.2$ U : Upper Specification Limit L : Lower Specification Limit	0/1
2	Temperature Cycle	H : +85°C 30mins ↑ 5mins ↓ L : -55°C 30mins	50Cycles	22pcs		0/1
3	Thermal Shock	H : +100°C 5mins ↑ 10secs ↓ L : -10°C 5mins	50Cycles	22pcs		0/1
4	High Temperature Storage	TEMP. : +100°C	1000hrs	22pcs		0/1
5	Low Temperature Storage	TEMP. : -55°C	1000hrs	22pcs		0/1
6	DC Operating Life	$I_F = 20mA$	1000hrs	22pcs		0/1
7	High Temperature/ High Humidity	85°C / 85% R.H	1000hrs	22pcs		0/1



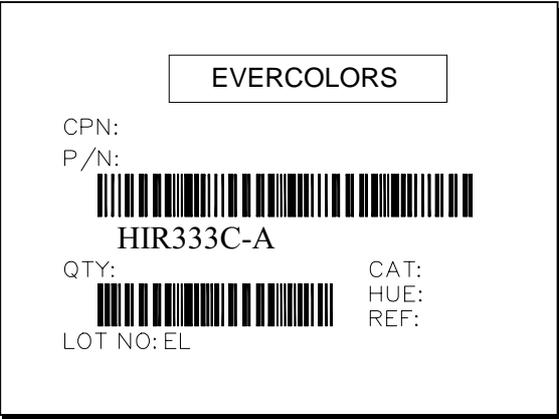
HIR333C-A

Packing Quantity Specification

1.500PCS/1Bag , 5Bags/1Box

2.10Boxes/1Carton

Label Form Specification



CPN: Customer's Production Number

P/N : Production Number

QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number